Supporting Information for

Syntheses, structures, and properties of sulfides constructed by SbS₄ teeter-totter polyhedron: Ba₃La₄Ga₂Sb₂S₁₅ and BaLa₃GaSb₂S₁₀

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Table S1. Atomic coordinates and equivalent isotropic displacement parameters of

Atom	Wyckoff	x	У	Z	U(eq)
Lal	8 <i>j</i>	0.05421(4)	0.3355(2)	1/2	0.0132(3)
La2	8 <i>j</i>	0.28521(4)	0.3660(2)	0.0000	0.0112(3)
Ba1	4 <i>a</i>	0.0000	0.0000	1/4	0.0146(3)
Ba2	8 <i>f</i>	0.16341(4)	1/2	3/4	0.0142(3)
Sb1	8 <i>j</i>	0.10175(6)	0.7872(2)	1/2	0.0316(4)
Gal	8 <i>f</i>	0.17035(6)	0.0000	1/4	0.0093(4)
S 1	16 <i>k</i>	0.1183(2)	0.1624(3)	0.3514(2)	0.0135(5)
S2	8 <i>j</i>	0.1671(2)	0.5021(4)	1/2	0.0137(8)
S 3	16 <i>k</i>	0.2240(2)	0.1506(3)	0.1435(2)	0.0142(5)
S4	16 <i>k</i>	0.0493(2)	0.6465(3)	0.6317(2)	0.0136(5)
S5	4c	0.0000	1.0000	1/2	0.0174(2)

compound 1 and 2.

Atom	Wyckoff	x	У	Z	U(eq)
Lal	2 <i>e</i>	0.6161(2)	1/4	0.05695(6)	0.0090(2)
La2	2 <i>e</i>	1.1157(2)	1/4	0.94309(6)	0.0088(2)
La3	2 <i>e</i>	1.8804(2)	1/4	0.69118(6)	0.0101(2)
La4	2 <i>e</i>	1.38044(2)	1/4	0.30897(6)	0.0097(2)
La5	4 <i>f</i>	1.24990(9)	-0.00004(6)	1.12751(4)	0.0145(2)
Ba1	4 <i>f</i>	2.24990(9)	-0.00003(6)	0.61748(4)	0.61748(4)
Gal	4 <i>f</i>	0.7501(2)	-0.0001(4)	0.12602(7)	0.0084(3)
Sb1	2 <i>e</i>	0.9526(2)	1/4	0.21986(7)	0.0138(3)
Sb2	2 <i>e</i>	1.5277 (2)	1/4	0.53715(7)	0.0139(3)
Sb3	2 <i>e</i>	2.0278(2)	1/4	0.46281(7)	0.0137(3)
Sb4	2 <i>e</i>	1.4524(2)	1/4	0.78022(7)	0.0141(3)
S 1	4 <i>f</i>	1.5975(4)	0.1085(2)	0.7132(2)	0.0132(6)
S2	2 <i>e</i>	0.7471(5)	1/4	-0.1220(2)	0.019(2)
S3	4 <i>f</i>	1.0975(4)	0.1077(2)	0.2870(2)	0.0142(6)
S4	2 <i>e</i>	0.2476(5)	1/4	0.1212(3)	0.020(2)
S5	4 <i>f</i>	0.9029(4)	0.1028(2)	0.0380(2)	0.0133(6)
S 6	4 <i>f</i>	1.0760(4)	0.1030(2)	0.8004(2)	0.0120(6)
S7	4 <i>f</i>	0.5763(4)	0.1028(2)	0.1028(2)	0.0119(6)
S 8	4 <i>f</i>	0.4021(4)	0.1018(2)	-0.0381 (2)	0.0128(6)
S9	4 <i>f</i>	1.9136(4)	0.1126(2)	0.5474 (2)	0.0134(6)
S10	4 <i>f</i>	0.0134(6)	0.1121(2)	0.4525(2)	0.0147(6)
S11	2 <i>e</i>	2.2639(5)	1/4	0.6346(3)	0.0183(9)
S12	2e	1.7643(5)	1/4	0.3656(3)	0.0170(9)

Table S2. Selected bond lengths (\AA) of compound 1 and 2.

1						
La1–S1×2	2.870(3)	Ba1–S1×4	3.370(3)	Sb1–S4×2	2.443(3)	
La1–S5	2.9398(9)	Ba1–S5×2	3.3976(2)	Sb1–S2	2.727(4)	
La1–S2	2.972(4)	Ba1–S4×4	3.422(3)	Sb1–S5	2.932(2)	
La1–S4×2	3.035(3)	Ba2–S1×2	3.182(3)	Ga1–S1×2	2.247(3)	
La1–S4×2	3.039(3)	Ba2–S3×2	3.254(3)	Ga1–S3×2	2.261(3)	
La2–S3×2	2.964(3)	Ba2–S4×2	3.345(3)			
La2–S2	2.979(4)	Ba2–S2×2	3.3988(2)			
La2–S3×2	2.982(3)	Ba2–S3×2	3.425(3)			
La2–S1×2	3.054(3)					
La2–S2	3.114(4)					

2						
La1–S2	2.940(4)	La5–S6	3.091(3)	Ga1–S6	2.243(3)	
La1–S8×2	2.982(4)	La5–S7	3.092(3)	Ga1–S7	2.246(3)	
La1–S7×2	2.984(3)	La5–S3	3.092(3)	Ga1–S8	2.260(3)	
La1–S5×2	2.997(3)	La5–S1	3.092(3)	Ga1–S5	2.275(3)	
La1–S4	3.024(4)	La5–S8	3.131(3)	Sb1–S3×2	2.454(3)	
La2–S4	2.928(5)	La5–S5	3.135(3)	Sb1-S12	2.681(5)	
La2–S5×2	2.970(3)	La5–S5	3.324(3)	Sb1–S4	2.747(4)	
La2–S6×2	2.978(3)	La5–S8	3.327(3)	Sb2-S10×2	2.439(3)	
La2–S8×2	3.003(3)	La5–S2	3.377(2)	Sb2-S11	2.539(4)	
La2–S2	3.026(4)	Ba1–S10	3.203(3)	Sb2-S12	3.219(5)	

La3–S9×2	2.902(3)	Ba1–S9×2	3.203(3)	Sb3–S9×2	2.435(3)
La3–S1×2	2.928(3)	Ba1–S10	3.221(3)	Sb3-S12	2.530(4)
La3–S6×2	3.011(3)	Ba1–S12	3.388(3)	Sb3–S11	3.216(5)
La3–S2	3.059(4)	Ba1–S11	3.389(2)	Sb4–S1×2	2.447(3)
La3–S11	3.098(5)	Ba1–S3	3.397(3)	Sb4–S11	2.675(5)
La4–S10×2	2.903(3)	Ba1–S1	3.401(3)	Sb4–S2	2.733(4)
La4–S3×2	2.935(3)	Ba1–S7	3.413(3)		
La4–S7×2	3.015(3)	Ba1–S6	3.421(3)		
La4–S4	3.069(5)				
La4–S12	3.098(4)				
La5–S6	3.091(3)				
La5–S7	3.092(3)				
La5–S3	3.092(3)				
La5–S1	3.092(3)				
La5–S8	3.131(3)				
La5–S5	3.135(3)				
La5–S5	3.324(3)				
La5–S8	3.327(3)				
La5–S2	3.377(2)				
La5–S4	3.379(2)				



Figure S1. The tester-totter polyhedron SbS_4 . Legend: yellow, S; blue, Sb.



Figure S2. The isolated finite complex anion constructed by SbX_4 (X = S, Se) teetertotter polyhedron connecting with other units in (a) $Ba_4LaGe_3SbSe_{13}$,¹ (b)

Ba₄Sb₃S₈Cl² and (c) Ba₈Sb₆S₁₇.³ Legend: blue, Sb; dark red, Ge; yellow, S or Se.



Figrue S3. Infinite chains constructed by SbX₄ (X = S, Se) teeter-totter polyhedron connecting with other units in (a) Pr₄GaSbS₉,⁴ (b) La₄InSbS₉,⁵ (c) La₄FeSb₂S₁₀,⁶ (d)
Ba₄SiSb₂Se₁₁,⁷ (e) Na₉Gd₅Sb₈S₂₆,⁸ (f) SrGeSb₂Se₈,⁹ and (g) BaSb₂S₄.¹⁰ Legend: blue, Sb; light blue, Ga; green, In; blue and dark red, Ge/Sb; yellow, S or Se.



Figure S4. Layers constructed by SbS_4 teeter-totter polyhedron connecting with other units in $La_2Ga_{0.33}SbS_5$,¹¹ RbU_2SbS_8 .¹² Legend: blue, Sb; red, U; yellow, S.



Figure S5. Experimental and simulated powder X-ray diffraction (XRD) data for (a) compound 1 and (b) 2.



Figure S6. The coordination environment of Ba and La with S atoms in compound **1** (The black, red and yellow balls represent Ba, La and S atoms, respectively)



Figure S7. The coordination environment of La and Ba with S in compound **2** (The black, red and yellow balls represent Ba, La and S atoms, respectively)



Figure S8. Calculated band structure of compound 1 (a) and 2 (b).



Figure S9. The Electron localization function (ELF) isofurfaces for the Sb–S bonds in compound **1** (a) and **2** (b). Contours are from 0.00 to 1.00.

Reference

- 1. A. Assoud, N. Soheilnia and H. Kleinke, J. Solid State Chem., 2004, 177, 2249.
- 2. H. J. Zhao, J. Solid State Chem., 2016, 235, 18.
- 3. W. Dorrscheidt and H. Schafer, Z. Naturforschung B, 2014, 36, 410.
- M. C. Chen, L. H. Li, Y. B. Chen and L. Chen, J. Am. Chem. Soc., 2011, 133, 4617.
- 5. H. J. Zhao, Y. F. Zhang and L. Chen, J. Am. Chem. Soc., 2012, 134, 1993.
- 6. H. J. Zhao, L. H. Li, L. M. Wu and L. Chen, Inorg. Chem., 2009, 48, 11518.
- 7. K. S. Choi and M. G. Kanatzidis, Inorg. Chem., 2001, 40, 101.

- 8. S. Park and S. J. Kim, J. Solid State Chem., 2001, 161, 129.
- C. Y. Yu, M. F. Wang, M. Y. Chung, S. M. Jang, J. C. Huang and C. S. Lee, *Solid State Sci.*, 2008, 10, 1145.
- 10. G. Cordier, C. Schwidetzky and H. Schafer, J. Solid State Chem., 1984, 54, 84.
- 11. H. J. Zhao, J. Solid State Chem., 2016, 237, 99.
- 12. K. S. Choi and M. G. Kanatzidis, Chem. Mater., 1999, 11, 2613.